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SEMICONDUCTOR®

April 2025

FQAF13N80 — N-Channel QFET® MOSFET

FQAF13N80

N-Channel QFET[®] MOSFET

 $800~V,\,8.0~A,\,750~m\Omega$

Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

G

Features

- + 8.0 A, 800 V, $R_{DS(on)}$ = 750 m Ω (Max.) @ V_{GS} = 10 V, I_{D} = 4.0 A
- Low Gate Charge (Typ. 68 nC)
- Low Crss (Typ. 30 pF)
- 100% Avalanche Teste



Absolute Max num Ratings 1200 unless otile, visc noted

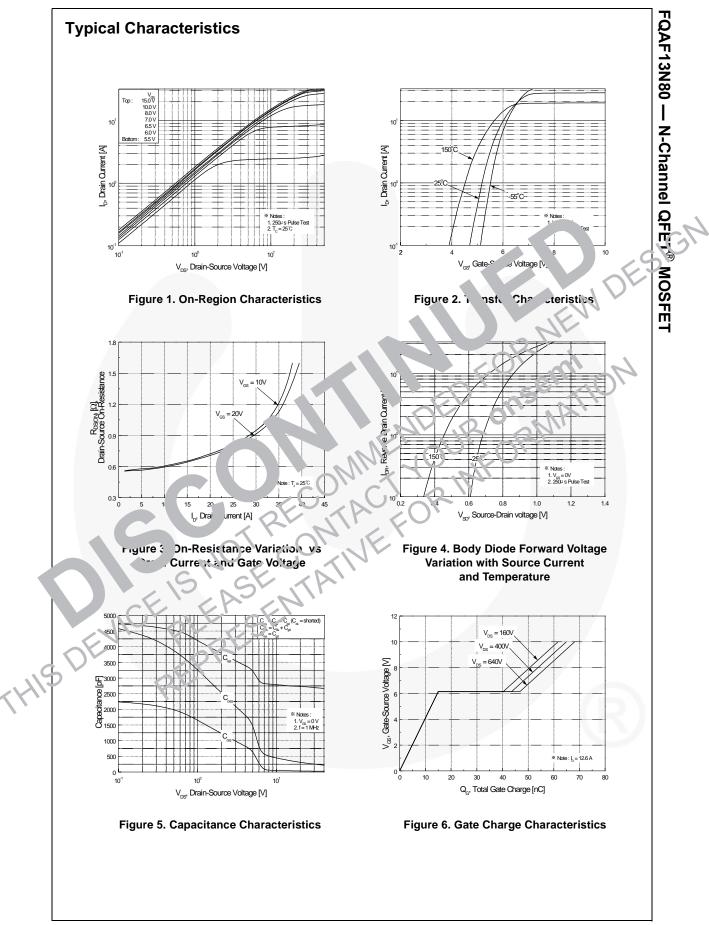
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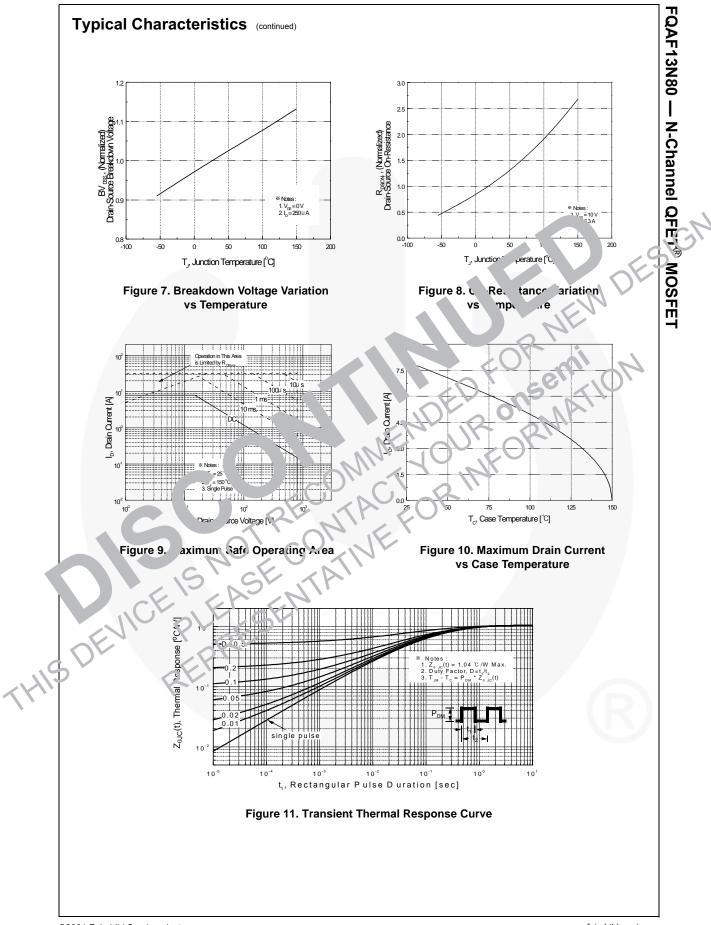
Symbo'	Part meier	Para meier		Unit		
V _{DS}	.an. ource Voltage		800	V		
	urrent - Continuou: (T ₁) = 25°	C)	8.0	A		
	- Continuous (T _C = 100	5.1	A			
I _{DM}	Drain Current Pulsed	(Note 1)	32	A		
Vr .	Gete Source Voitage		± 30			
-AS	Single Fulsed Avalancies Energy	(Note 2)	1100	mJ		
I _{AR}	Avalanche Curren	(Note 1)	8.0	A		
E _A	Repetitive / valar che Energy	(Note 1)	12	mJ		
dv/dt	Peak Divde Recovery dv/dt	(Note 3)	4.0	V/ns		
P _D	Power Dissipation (T _C = 25°C)		120	W		
	- Derate above 25°C	0.96	W/°C			
T _J , T _{STG}	Operating and Storage Temperature Rar	nge	-55 to +150	°C		
ΤL	Maximum lead temperature for soldering 1/8" from case for 5 seconds	l purposes,	300	°C		

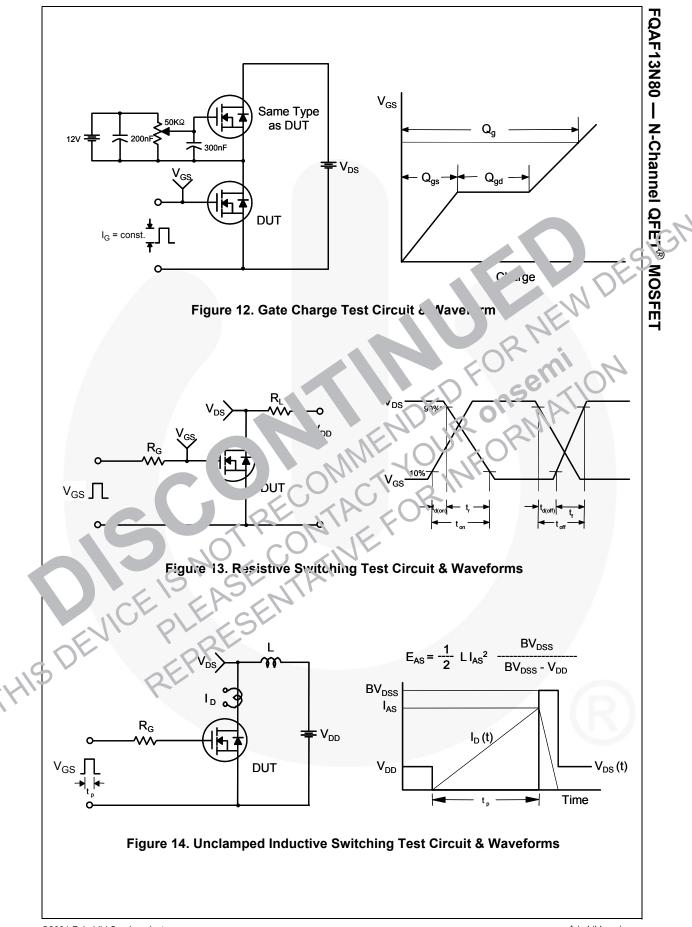
Thermal Characteristics

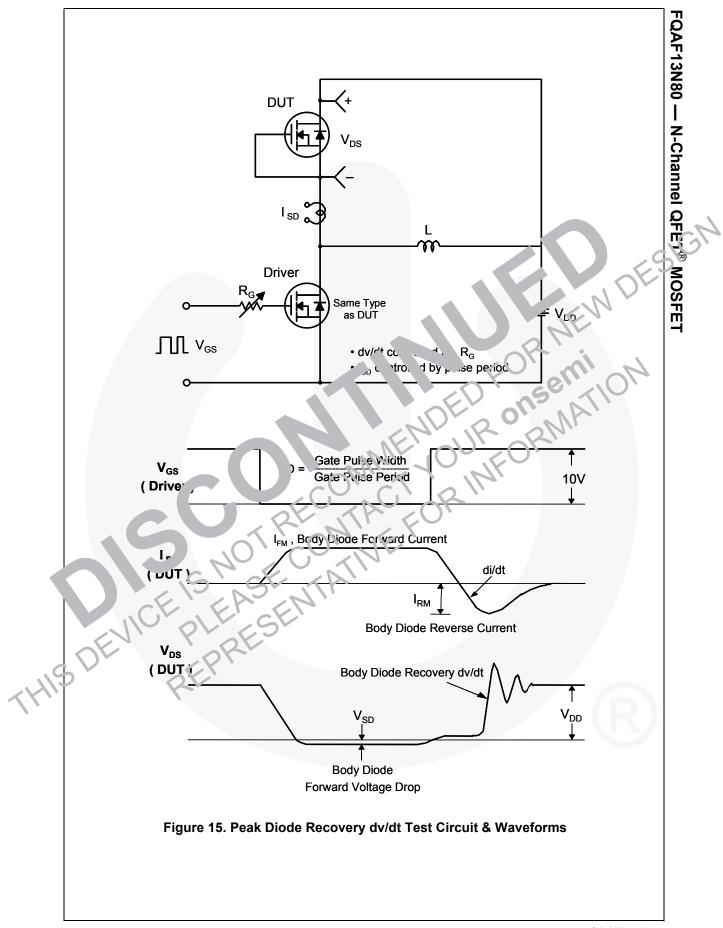
Symbol	Parameter	FQAF13N80	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction-to-Case, Max.	1.04	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	40	°C/W

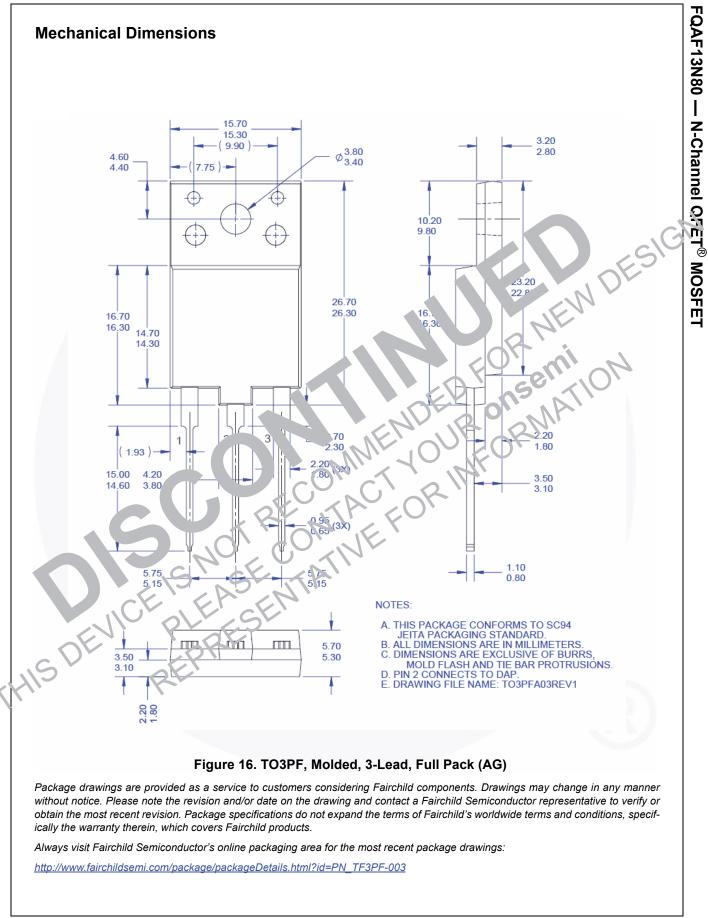
		ackage	Packing Method	Reel Si	ze	Tape W		Quanti
FQAF13	N80 FQAF13N80 T	O-3PF	Tube	N/A		N/A		30 unit
Electri	cal Characteristics T _c = 25°0	C unless otherwi	ise noted.					
Symbol	Parameter		Test Conditions		Min	Тур	Мах	Unit
Off Cha	racteristics							
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0$	0 V, I _D = 250 μA	-	800			V
ΔBV_{DSS} / ΔT_{J}	Breakdown Voltage Temperature Coefficient	I _D = 25	$0 \mu A$, Referenced to	25°C		0.95		V/°(
I _{DSS}	Zero Gate Voltage Drain Current		800 V, V _{GS} = 0 V 640 V, T _C = 125°C				10 10	μΑ μΑ
I _{GSSF}	Gate-Body Leakage Current, Forwar		30 V, V _{DS} = 0 V				100	nA
I _{GSSR}	Gate-Body Leakage Current, Revers		-30 V, V _{DS} = 0 V		7		101	nA
	racteristics						<u> </u>	7
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V	V _{GS} , I _D = 250 יי A		0		5.0	T v
R _{DS(on)}	Static Drain-Source On-Resistance		0V, I _D = 10 A			୦.58	0.75	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 4			C	10.5		S
Dynami	c Characteristics			Ω		Se	く	0
C _{iss}	Input Capacitance	$V_{DS} = 2$	$2 V_{\rm GS} = 0.7$		O	2700	3:-00	pF
C _{oss}	Output Capacitance		Mhz		-	27.s	360	pF
C _{rss}	Reverse Transfer Capar		AL	<u>N</u>	Ē	30	39	pF
Switchi	ng Characteristic	10	VI. 10	L.				
t _{d(on)}	Turn-On C ay Time		400 V, I_{f} = 12.6 A.			60	130	ns
tr	Turn-On F e Time	$-$ DD = $R_{\rm G} = 2$				150	310	ns
t _{d(off)}	In-Off De Tim					155	320	ns
t _f	Il Time			(Note 4)		110	230	ns
0	Total Ga' Charge		340 V, I _D = 12.6 A,			68	88	nC
Q _{gs}	Pate-Source Charge	109=				15		nC
Q _{gd}	Uate-Drain Charge	7.V.	((Note 4)		32		nC
i ain-S	ource Dicde Characteristics	and Max	imum Ratings					
Is	Maximum Continuous L ain-Source	Diode Forw	ard Current				8.0	Α
'SM	Maximum Pulsed Drain-Source Dioc	le Forward C	Current				36	A
V _{SD}	Drain-Source Diode Forward Voltage		0 V, I _S = 8.0 A				1.4	V
t _{rr}	Reverse Recovery Time		0 V, I _S = 12.6 A,			850		ns
Q _{rr}	Reverse Recovery Charge	dl _F / dt	= 100 A/μs			11.3		μC













	1 0	may change in any manner without notice.
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		Rev. 166

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